NSN 5962-01-344-4999

Memory Microcircuit - Page 1 of 2

Overall Length:



View Online at https://aerobasegroup.com/nsn/5962-01-344-4999

Overall Height: 0.432 inches Body Length: 1.490 inches Body Width: Between 0.500 inches and 0.610 inches Body Height: Between 0.172 inches and 0.217 inches Maximum Power Dissipation Rating: 1.0 watts Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: W/disable and w/inhibit and w/enable and monolithic and ultraviolet erasable and programmable Inclosure Material: Ceramic Inclosure Configuration: Dual-in-line Output Logic Form: Metal oxide-semiconductor logic Input Circuit Pattern: 17 input Case Outline Source And Designator: D-10 mill-m-38510 Current Rating Per Characteristic: 125.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic:
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125.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder
Terminal Surface Treatment: Solder
Solder
Voltage Rating And Type Per Characteristic:
-0.6 volts power source and 6.25 volts power source
Capitance Rating Per Characteristic:
Err-060 and err-060
Time Rating Per Chacteristic:
200.00 nanoseconds access
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.

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T	erm	inal	Type	Δnd	Ou	antity	,.
ı	GIIII	ıııaı	IVDE	Allu	чu	annını	

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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